
2SK2431

Silicon N-Channel MOS FET

HITACHI

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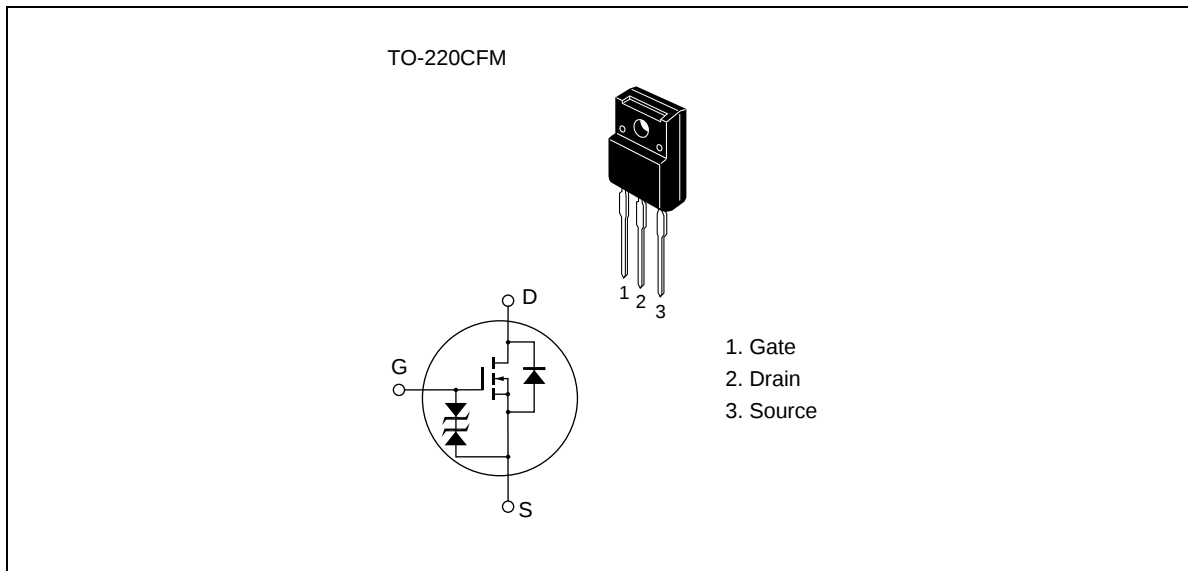
Application

High speed power switching

Features

- Low on-resistance
- High speed switching
- Low drive current
- No Secondary Breakdown
- Suitable for Switching regulator, DC-DC converter.

Outline



2SK2431

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	450	V
Gate to source voltage	V_{GSS}	±30	V
Drain current	I_D	3	A
Drain peak current	$I_{D(pulse)}^{*1}$	12	A
Body to drain diode reverse drain current	I_{DR}	3	A
Channel dissipation	P_{ch}^{*2}	25	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	–55 to +150	°C

Notes 1. $PW \leq 10 \mu s$, duty cycle $\leq 1 \%$
2. Value at Tc = 25 °C

Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	450	—	—	V	$I_D = 10 \text{ mA}$, $V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	± 30	—	—	V	$I_G = \pm 100 \text{ }\mu\text{A}$, $V_{DS} = 0$
Gate to source leak current	I_{GSS}	—	—	± 10	μA	$V_{GS} = \pm 25 \text{ V}$, $V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	250	μA	$V_{DS} = 450 \text{ V}$, $V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	2.0	—	3.0	V	$I_D = 1 \text{ mA}$, $V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	$R_{DS(on)}$	—	2.0	2.8	Ω	$I_D = 2 \text{ A}$ $V_{GS} = 10 \text{ V}^{*1}$
Forward transfer admittance	$ y_{fs} $	1.5	2.5	—	S	$I_D = 2 \text{ A}$ $V_{DS} = 10 \text{ V}^{*1}$
Input capacitance	C_{iss}	—	330	—	pF	$V_{DS} = 10 \text{ V}$ $V_{GS} = 0$ $f = 1 \text{ MHz}$
Output capacitance	C_{oss}	—	90	—	pF	
Reverse transfer capacitance	C_{rss}	—	15	—	pF	
Turn-on delay time	$t_{d(on)}$	—	7	—	ns	$I_D = 2 \text{ A}$ $V_{GS} = 10 \text{ V}$ $R_L = 15 \Omega$
Rise time	t_r	—	20	—	ns	
Turn-off delay time	$t_{d(off)}$	—	30	—	ns	
Fall time	t_f	—	20	—	ns	
Body to drain diode forward voltage	V_{DF}	—	0.9	—	V	$I_F = 3 \text{ A}$, $V_{GS} = 0$
Body to drain diode reverse recovery time	t_{rr}	—	300	—	ns	$I_F = 3 \text{ A}$, $V_{GS} = 0$, $diF / dt = 100 \text{ A} / \mu\text{s}$

Note 1. Pulse Test

See characteristics curves of 2SK1153, 2SK1862.

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